V10PWM45

Vishay General Semiconductor

High Current Density Surface-Mount TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.38$ V at $I_F = 5$ A



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SlimDPAK (TO-252AE)



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	10 A				
V _{RRM}	45 V				
I _{FSM}	180 A				
V _F at I _F = 10 A (T _J = 125 °C)	0.46 V				
T _J max.	175 °C				
Package	SlimDPAK (TO-252AE)				
Circuit configuration	Single				

FEATURES

- Very low profile typical height of 1.3 mm
- Trench MOS Schottky technology
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V10PWM45	UNIT	
Device marking code		V10PWM45		
Maximum repetitive peak reverse voltage	V _{RRM}	45	V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)} ⁽¹⁾	10	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	180	А	
Operating junction temperature range	T _J ⁽²⁾	-40 to +175	°C	
Storage temperature range	T _{STG}	-55 to +175	°C	

Notes

⁽¹⁾ With infinite heatsink

 $^{(2)}$ The heat generated must be less than the thermal conductivity from junction to ambient: $dP_D/dT_J < 1/R_{\theta JA}$

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ROHS COMPLIANT

HALOGEN

V10PWM45



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ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 5.0 A	T _J = 25 °C	VF ⁽¹⁾	0.49	-	V
	I _F = 10 A			0.55	0.59	
	I _F = 5.0 A	T _J = 125 °C		0.38	-	
	I _F = 10 A			0.46	0.51	
Reverse current	N 45 M	$T_{J} = 25 °C$	I _R ⁽²⁾	-	0.1	mA
	V _R = 45 V	T _J = 125 °C		3	10	
Typical junction capacitance	4.0 V, 1 MHz		CJ	1900	-	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V10PWM45	UNIT
Typical thermal resistance	R _{0JA} (1)(2)	65	°C/W
	R _{0JM} ⁽³⁾	2.5	0/10

Notes

 $^{(1)}$ The heat generated must be less than thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

⁽²⁾ Free air, mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ - junction to ambient

 $^{(3)}$ Mounted on infinite heat sink; thermal resistance $R_{\theta JM}$ - junction-to-mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V10PWM45-M3/I	0.20	I	4500	13" diameter plastic tape and reel		
V10PWM45HM3/I ⁽¹⁾	0.20	l	4500	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

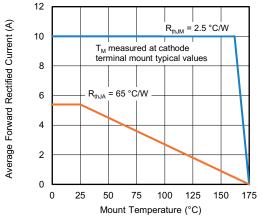


Fig. 1 - Maximum Forward Current Derating Curve

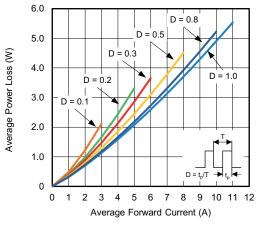


Fig. 2 - Forward Power Loss Characteristics

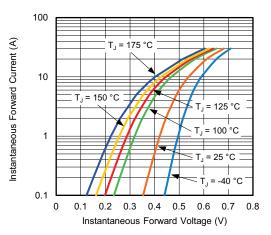


Fig. 3 - Typical Instantaneous Forward Characteristics

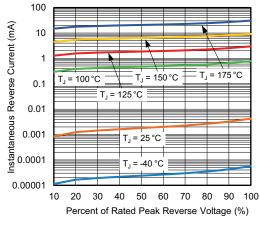


Fig. 4 - Typical Reverse Leakage Characteristics

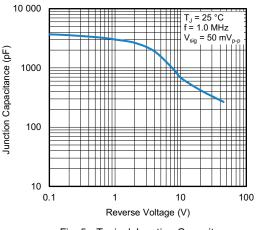


Fig. 5 - Typical Junction Capacitance

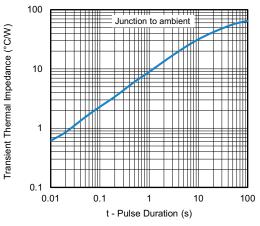


Fig. 6 - Typical Transient Thermal Impedance

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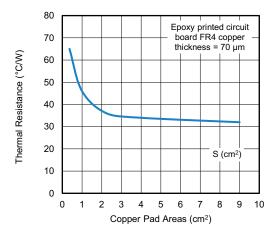
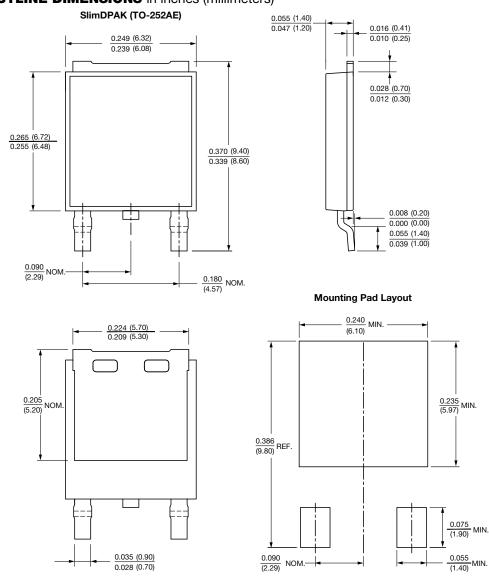


Fig. 7 - Typical Resistance Junction to Ambient vs. Copper Pad Areas



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